# **DISCRETE SEMICONDUCTORS**

# DATA SHEET

**PEMB13; PUMB13** PNP/PNP resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 47 kΩ

Product data sheet Supersedes data of 2003 Dec 11 2004 Apr 15



# PNP/PNP resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

PEMB13; PUMB13

#### **FEATURES**

- Built-in bias resistors
- · Simplified circuit design
- · Reduction of component count
- · Reduced pick and place costs.

## **APPLICATIONS**

- · Low current peripheral drivers
- Replacement of general purpose transistors in digital applications
- · Control of IC inputs.

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	_	-50	>
I <sub>O</sub>	output current (DC)	_	-100	mA
TR1	PNP	_	_	
TR2	PNP	_	-	_
R1	bias resistor	4.7	_	kΩ

47

 $k\Omega$ 

**QUICK REFERENCE DATA** 

bias resistor

## **DESCRIPTION**

PNP/PNP resistor-equipped transistors (see "Simplified outline, symbol and pinning" for package details).

## **PRODUCT OVERVIEW**

TYPE NUMBER	PACKAGE		MARKING CODE	NPN/PNP	NPN/NPN	
TIPE NOMBER	PHILIPS	EIAJ	WARKING CODE	COMPLEMENT	COMPLEMENT	
PEMB13	SOT666	-	45	PEMD13	PEMH13	
PUMB13	SOT363	SC-88	B*5	PUMD13	PUMH13	

R2

## Note

- 1. \* = p: Made in Hong Kong.
  - \* = t: Made in Malaysia.
  - \* = W: Made in China.

# SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PINNING		
ITPE NUMBER	SIMPLIFIED OUTLINE AND STMBOL	PIN	DESCRIPTION	
PEMB13	6 5 4	1	emitter TR1	
PUMB13	6 5 4	2	base TR1	
	R1 R2 TR2	3	collector TR2	
		4	emitter TR2	
		5	base TR2	
		6	collector TR1	
	1 2 3 Top view MAM477			
	1 OP VICHY INFINITY			

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## **ORDERING INFORMATION**

TYPE NUMBER		PACKAGE	
ITPE NUMBER	NAME DESCRIPTION		VERSION
PEMB13	_	plastic surface mounted package; 6 leads	SOT666
PUMB13	_	plastic surface mounted package; 6 leads SC	

## **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
Per transi	stor	-	<b>'</b>	<b>-</b>	-
$V_{CBO}$	collector-base voltage	open emitter	_	-50	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-50	V
V <sub>EBO</sub>	emitter-base voltage	open collector	-	-10	V
VI	input voltage				
	positive		_	+5	V
	negative		_	-30	V
I <sub>O</sub>	output current (DC)		_	-100	mA
I <sub>CM</sub>	peak collector current		-	-100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT363	note 1	_	200	mW
	SOT666	notes 1 and 2	_	200	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C
Per device	•				
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C			
	SOT363	note 1	_	300	mW
	SOT666	notes 1 and 2	_	300	mW

## **Notes**

- 1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
- 2. Reflow soldering is the only recommended soldering method.

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## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
Per transis	tor			
R <sub>th j-a</sub>	thermal resistance from junction to ambient	T <sub>amb</sub> ≤ 25 °C		
	SOT363	note 1	625	K/W
	SOT666	notes 1 and 2	625	K/W
Per device				
R <sub>th j-a</sub>	thermal resistance from junction to ambient	T <sub>amb</sub> ≤ 25 °C		
	SOT363	note 1	416	K/W
	SOT666	note 1	416	K/W

#### **Notes**

- 1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
- 2. Reflow soldering is the only recommended soldering method.

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0$	-	_	-100	nA
I <sub>CEO</sub>	collector-emitter cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0$	_	_	-1	μΑ
		$V_{CE} = -30 \text{ V}; I_{B} = 0; T_{j} = 150 ^{\circ}\text{C}$	_	_	-50	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V; } I_{C} = 0$	_	_	-170	μΑ
h <sub>FE</sub>	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -10 \text{ mA}$	100	_	_	
V <sub>CEsat</sub>	saturation voltage	$I_C = -5 \text{ mA}; I_B = -0.25 \text{ mA}$	-	_	-100	mV
$V_{i(off)}$	input-off voltage	$V_{CE} = -5 \text{ V}; I_{C} = -100 \mu\text{A}$	-	-0.6	-0.5	V
V <sub>i(on)</sub>	input-on voltage	$V_{CE} = -0.3 \text{ V}; I_{C} = -5 \text{ mA}$	-1.3	-0.9	_	V
R1	input resistor		3.3	4.7	6.1	kΩ
<u>R2</u> R1	resistor ratio		8	10	12	
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = -10 \text{ V}$ ; $f = 1 \text{ MHz}$	_	_	3	pF

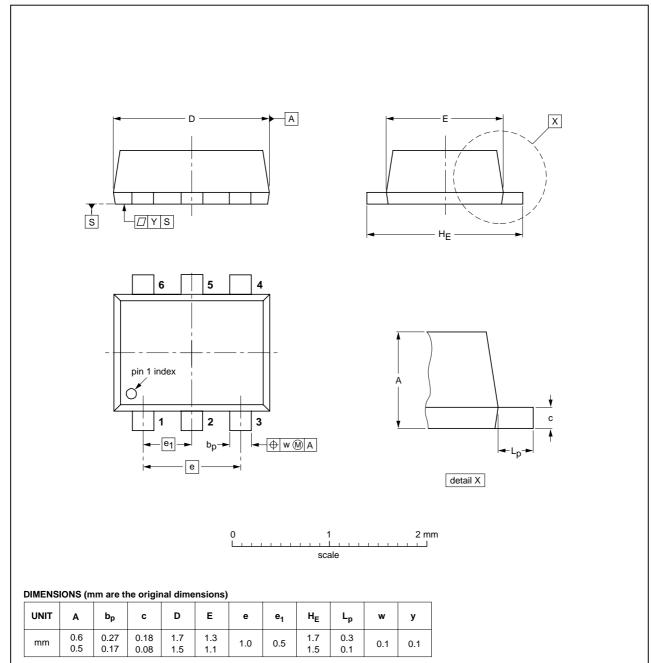
# PNP/PNP resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

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# **PACKAGE OUTLINES**

# Plastic surface-mounted package; 6 leads

SOT666



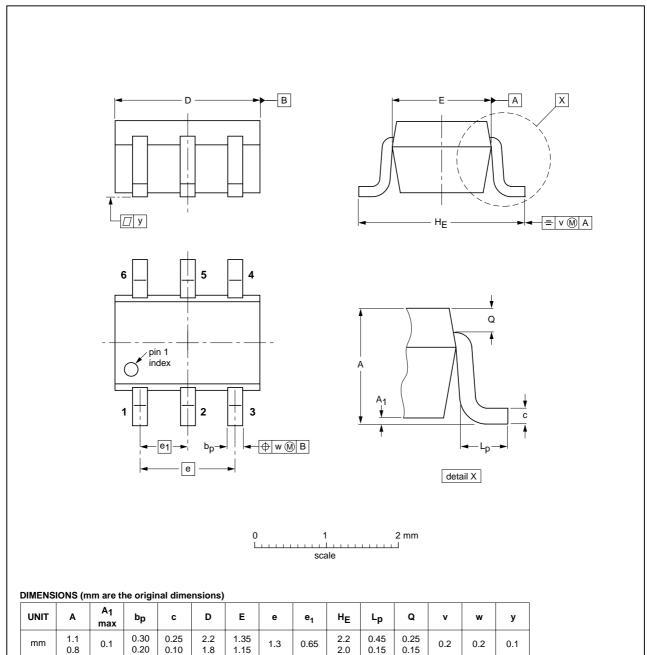
REFERENCES			EUROPEAN	ISSUE DATE	
IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
					<del>-04-11-08-</del> 06-03-16
-	IEC	IEC JEDEC	IEC JEDEC JEITA	IEC JEDEC JEITA	IEC JEDEC JEITA PROJECTION

# PNP/PNP resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

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# Plastic surface-mounted package; 6 leads

**SOT363** 



OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT363			SC-88			<del>-04-11-08-</del> 06-03-16

# PNP/PNP resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 47 k $\Omega$

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#### **DATA SHEET STATUS**

DOCUMENT STATUS <sup>(1)</sup>	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

#### **Notes**

- 1. Please consult the most recently issued document before initiating or completing a design.
- 2. The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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# **NXP Semiconductors**

## **Customer notification**

This data sheet was changed to reflect the new company name NXP Semiconductors, including new legal definitions and disclaimers. No changes were made to the technical content, except for package outline drawings which were updated to the latest version.

#### **Contact information**

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